30 V, 0.7 A, Low V_{CE(sat)} NPN Transistor

ON Semiconductor's e^2 PowerEdge family of low $V_{CE(sat)}$ transistors are miniature surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical application are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

• This is a Pb-Free Device

MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

| Rating | Symbol | Value | Unit |
|---|--|-------------------|------------------|
| Collector-Emitter Voltage | V _{CEO} | 30 | V |
| Collector-Base Voltage | V _{CBO} | 40 | V |
| Emitter-Base Voltage | V _{EBO} | 5.0 | V |
| Collector Current | I _C | 700 | mA |
| Base Current | I _B | 350 | mA |
| Total Power Dissipation @ T _C = 25°C Total Power Dissipation @ T _C = 85°C Thermal Resistance – Junction–to–Ambient (Note 1) | P _D P _D R _{θJA} | 342 178 366 | mW mW °C/W |
| Total Power Dissipation @ T _C = 25°C Total Power Dissipation @ T _C = 85°C Thermal Resistance – Junction–to–Ambient (Note 2) | P _D P _D R _{θJA} | 665 346 188 | mW mW °C/W |
| Operating and Storage Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

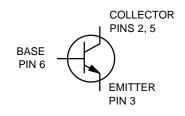
- 1. Minimum FR-4 or G-10 PCB, Operating to Steady State.
- Mounted onto a 2" square FR-4 Board (1" sq 2 oz Cu 0.06" thick single sided), Operating to Steady State.



ON Semiconductor®

http://onsemi.com

$\begin{array}{c} 30 \text{ VOLTS} \\ 0.7 \text{ AMPS} \\ \text{NPN LOW V}_{\text{CE(sat)}} \text{ TRANSISTOR} \\ \text{EQUIVALENT R}_{\text{DS(on)}} \text{ 200 m} \Omega \end{array}$





SC-74 CASE 318F STYLE 2

DEVICE MARKING



VS3 = Specific Device Code M = Date Code

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|--------------------|-----------------------|
| NSS30071MR6T1G | SC-74 (Pb-Free) | 10000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure. BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

| Symbol | Char | Min | Тур | Max | Unit | | | |
|----------------------|--|---|-----|-----|-----------|------|--|--|
| OFF CHAP | OFF CHARACTERISTICS | | | | | | | |
| V _{(BR)CBO} | Collector - Base Breakdown Voltage | (I _C = 100 μAdc) | 40 | - | _ | Vdc | | |
| V _{(BR)CEO} | Collector - Emitter Breakdown Voltage | (I _C = 10 mAdc) | 30 | - | - | Vdc | | |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | (I _E = 100 μAdc) | 5.0 | - | - | Vdc | | |
| I _{CBO} | Collector Cutoff Current | $(V_{CB} = 25 \text{ Vdc}, I_E = 0 \text{ Adc})$ $(V_{CB} = 25 \text{ Vdc}, I_E = 0 \text{ Adc}, T_A = 125^{\circ}\text{C})$ | - | | 1.0 10 | μAdc | | |
| I _{EBO} | Emitter Cutoff Current | (V _{EB} = 5.0 Vdc, I _C = 0 Adc) | _ | - | 10 | μAdc | | |
| ON CHARACTERISTICS | | | | | | | | |
| h _{FE} | DC Current Gain | $(V_{CE} = 3.0 \text{ Vdc}, I_{C} = 100 \text{ mAdc})$ | 150 | - | - | Vdc | | |
| V _{CE(sat)} | Collector - Emitter Saturation Voltage | $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$ | _ | - | 0.25 | Vdc | | |
| V _{CE(sat)} | Collector - Emitter Saturation Voltage | (I _C = 700 mAdc, I _B = 70 mAdc) | _ | - | 0.4 | Vdc | | |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | $(I_C = 700 \text{ mAdc}, I_B = 70 \text{ mAdc})$ | - | - | 1.1 | Vdc | | |
| V _{BE(on)} | Collector-Emitter Saturation Voltage | (I _C = 700 mAdc, V _{CE} = 1.0 Vdc) | _ | - | 1.0 | Vdc | | |

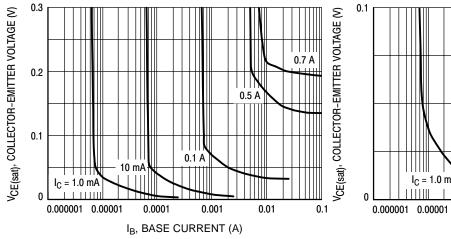


Figure 1. Collector Saturation Region

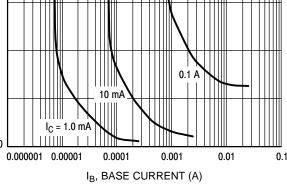


Figure 2. Collector Saturation Region

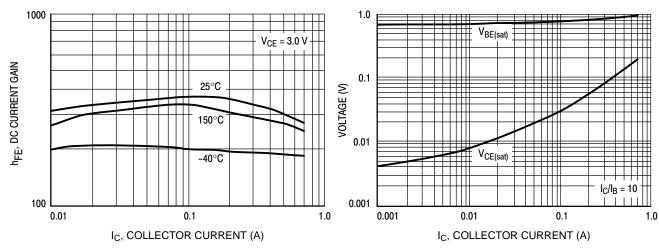


Figure 3. DC Current Gain

Figure 4. "ON" Voltages

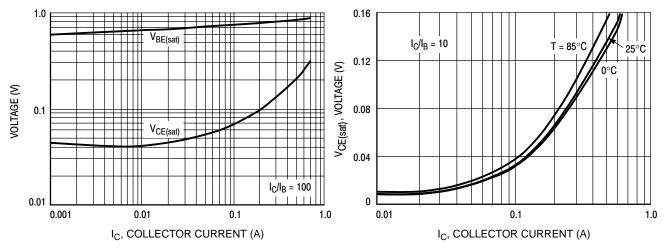


Figure 5. "ON" Voltages

Figure 6. Collector-Emitter Saturation Voltage

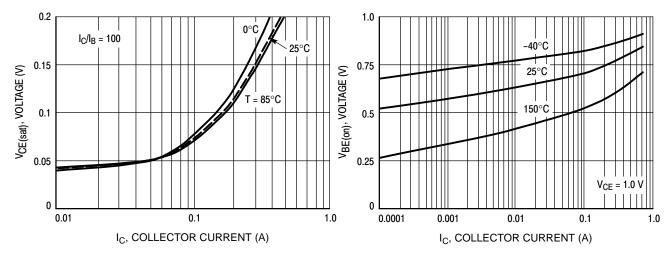


Figure 7. Collector-Emitter Saturation Voltage

Figure 8. V_{BE(on)} Voltage

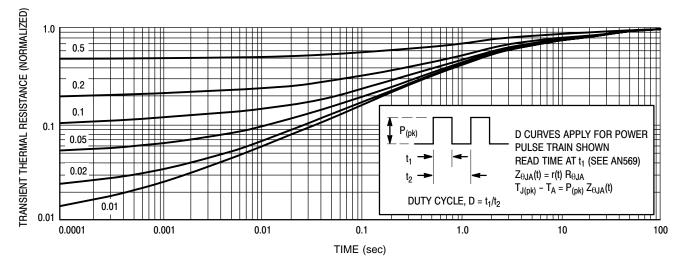


Figure 9. Thermal Response Curve





CTVLE 1.

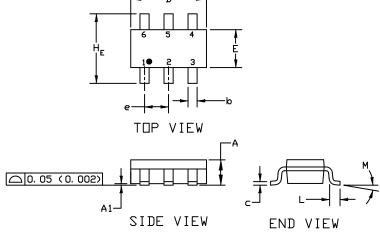
SC-74 CASE 318F ISSUE P

DATE 07 OCT 2021

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
- 2. CONTROLLING DIMENSION: INCHES
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.

| | MILLIMETERS | | | INCHES | | |
|----------------|-------------|-------|-------|--------|--------|--------|
| DIM | MIN. | N□M. | MAX. | MIN. | N□M. | MAX. |
| A | 0. 90 | 1. 00 | 1. 10 | 0. 035 | 0. 039 | 0. 043 |
| A1 | 0. 01 | 0. 06 | 0. 10 | 0. 001 | 0. 002 | 0. 004 |
| b | 0. 25 | 0. 37 | 0. 50 | 0. 010 | 0. 015 | 0. 020 |
| С | 0.10 | 0. 18 | 0. 26 | 0. 004 | 0. 007 | 0. 010 |
| D | 2. 90 | 3. 00 | 3. 10 | 0. 114 | 0. 118 | 0. 122 |
| E | 1. 30 | 1. 50 | 1. 70 | 0. 051 | 0. 059 | 0. 067 |
| е | 0. 85 | 0. 95 | 1. 05 | 0. 034 | 0. 037 | 0. 041 |
| Η _E | 2. 50 | 2. 75 | 3. 00 | 0. 099 | 0. 108 | 0. 118 |
| L | 0. 20 | 0. 40 | 0. 60 | 0. 008 | 0. 016 | 0. 024 |
| М | 0* | | 10* | 0* | | 10* |



GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

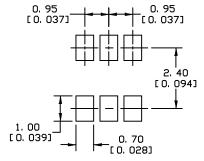
CTVLE O

■ = Pb-Free Package

(Note: Microdot may be in either location)

This information is generic. Please refer to

CTVI F O



For additional information on our Pb-Free strategy and soldering details, please download the UN Seniconductor Soldering and Mounting Techniques Reference Manual, SULDERRM/D.

SOLDERING FOOTPRINT

CTVLE 6

CTVLE F.

| STYLE 1: | STYLE 2: | STYLE 3: | STYLE 4: | STYLE 5: | STYLE 6: |
|--|--|--|--|--|---------------------------|
| PIN 1. CATHODE | PIN 1. NO CONNECTION | PIN 1. EMITTER 1 | PIN 1. COLLECTOR 2 | PIN 1. CHANNEL 1 | PIN 1. CATHODE |
| 2. ANODE | 2. COLLECTOR | 2. BASE 1 | 2. EMITTER 1/EMITTER 2 | 2. ANODE | ANODE |
| CATHODE | EMITTER | COLLECTOR 2 | COLLECTOR 1 | CHANNEL 2 | CATHODE |
| CATHODE | NO CONNECTION | EMITTER 2 | 4. EMITTER 3 | CHANNEL 3 | CATHODE |
| 5. ANODE | COLLECTOR | 5. BASE 2 | BASE 1/BASE 2/COLLECTOR 3 | CATHODE | CATHODE |
| CATHODE | 6. BASE | COLLECTOR 1 | 6. BASE 3 | CHANNEL 4 | CATHODE |
| STYLE 7: PIN 1. SOURCE 1 2. GATE 1 3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1 | STYLE 8: PIN 1. EMITTER 1 2. BASE 2 3. COLLECTOR 2 4. EMITTER 2 5. BASE 1 6. COLLECTOR 1 | STYLE 9: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2 | STYLE 10: PIN 1. ANODE/CATHODE 2. BASE 3. EMITTER 4. COLLECTOR 5. ANODE 6. CATHODE | STYLE 11: PIN 1. EMITTER 2. BASE 3. ANODE/CATHODI 4. ANODE 5. CATHODE 6. COLLECTOR | E |

CTVLE 4.

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| DESCRIPTION: | SC-74 | | PAGE 1 OF 1 |

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